



High optical nonlinearity in low-dimensional halide perovskite polycrystalline films

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Abstract: The nonlinear optical properties of low-dimensional polycrystalline halide perovskite films consisting of ethylammonium (EA) and butylammonium (BA) cations are investigated using Z-scan technique. Across the band-edge, two-dimensional (BA)₂PbI₄ exhibits a transition from saturable absorption (SA) to reverse-SA and its nonlinear absorption and nonlinear refractive index are much smaller than those of bulk counterparts. Meanwhile, EAPbI₃ with one-dimensionality of the inorganic structure shows the SA behavior both above and below band-edge and the estimated nonlinear optical parameters of polycrystalline EAPbI₃ are comparable to those of single-crystalline ones, attributed to high dielectric contrast between the inorganic and organic elements in one-dimensional structures.

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1. Introduction

Depending on the choice of organic and inorganic elements, metal halide perovskites can have tunable bandgaps and different structural forms. Recently, low-dimensional (0D, 1D or 2D) halide perovskites realized by introducing long chained cations as barriers between inorganic octahedra frameworks have attracted much attention owing to their excellent optical properties for photovoltaic and optoelectronic applications [1–5]. In particular, strong quantum confinement effect in low-dimensional halide perovskites enables the tunable and narrow excitonic emission at room temperature. Furthermore, exciton effect in low-dimensional perovskites leads to higher nonlinear optical responses than those in three-dimensional phase [6–9]. High formation energy, as well as the hydrophobic property of organic cations, also improve the stability of low-dimensional perovskites in an ambient atmosphere, extending their commercial utility into new areas such as large area, stable nonlinear optical devices [10].

All-optical switches based on nonlinear optics operate at high speeds and provide broad bandwidth unattainable by conventional electronic switches. Nonlinear materials used for optical switches are required to have not only large optical nonlinearity, but also fast carrier recovery time. In this work, we have investigated the nonlinear optical properties of low-dimensional perovskites consisting of the two alkylammonium cations, n-butylammonium (BA) and monoethylammonium (EA), near the bandgap using the conventional Z-scan method. Utilization of BA and EA cations results in the formation of 2D layered and 1D chain-like perovskites with bandgaps near 2.35 eV [11], allowing the development of nonlinear optical devices operating in visible spectral range. However, the reported values of nonlinear optical parameters (both nonlinear absorption coefficient and nonlinear refractive index) of low-dimensional perovskites are widely scattered due to the variation in crystalline quality of perovskites and moreover, their crystal

structure-dependence have not yet been reported [6–9]. To date, the highest optical nonlinearities for low-dimensional perovskites have been reported for single-crystalline perovskite nanosheets [9], but engineering of these nanosheets using mechanical exfoliation method from bulks hampers the development of large-scale nonlinear optical devices. Our results on $(\text{BA})_2\text{PbI}_4$ thin films show that the optical nonlinearity is still influenced by the crystalline quality of films and the estimated nonlinear optical parameters are smaller than those of single-crystalline counterparts [9]. Meanwhile, despite its polycrystalline nature, 1D EAPbI_3 thin films exhibit much larger optical nonlinearity at lower input intensities than $(\text{BA})_2\text{PbI}_4$ films and its value is comparable to that of single-crystalline perovskite nanosheets. Ultrafast pump-probe experiment shows that both EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ exhibit optical bleaching and the recovery times are less than a few picoseconds, which makes them an excellent candidate to realize the ultrafast all-optical switching.

2. Experimental methods

The EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ perovskite films were synthesized by spin-coating method as previously described [11]. Briefly, precursor solutions were prepared by dissolving the precursor chemicals in a solvent mixture of *N,N*-Dimethylformamide (DMF, anhydrous, 99.9+%, Alfa Aesar) and dimethyl sulfoxide (DMSO, anhydrous, 99.8+ %, Alfa Aesar) at a concentration of 0.5M. For the preparation of EAPbI_3 , ethyl ammonium iodide (EAI, Greatcell Solar Ltd.) and PbI_2 (99.9985%, Alfa Aesar) were dissolved in a molar ratio of 1:1 in the mixture of DMF and DMSO (5:1 volume ratio). For $(\text{BA})_2\text{PbI}_4$, *n*-butylammonium iodide (BAI, Greatcell Solar Ltd.) and PbI_2 are dissolved in a molar ratio of 2:1 in the solvent mixture of DMF and DMSO (3:1 volume ratio). Before spin-coating, the substrates were sonicated for 10 min in acetone, toluene, acetone, ethanol, and deionized water, respectively, and treated with oxygen plasma immediately before use. The films were then prepared by spin-coating the precursor solution on clean substrates at 5000 rpm for 30 s inside an argon-filled glovebox, followed by drying in low vacuum for 1 min. and annealing at 120 °C for 10 min to remove the solvent. In order to prevent degradation of samples in an ambient environment, all perovskite samples used in our study were encapsulated by a thin quartz glass. The morphology of perovskites was studied by scanning electron microscopy (SEM, JSM-7000F) and their crystal structures were investigated by using an X-ray diffractometer (XRD, Bede D1) with monochromatic Cu-K α radiation ($\lambda=1.5406 \text{ \AA}$). Le-Bail fitting was used for indexing and determination of the lattice parameters. The third-order nonlinear absorption coefficient (β) and nonlinear refraction coefficient (n_2) were obtained via open-aperture (OA) and closed-aperture (CA) Z-scan configurations [12]. Two photodetectors are used for simultaneous measurement of OA and CA signals during the scanning process. A femtosecond Ti:sapphire laser (1 kHz repetition rate and 100 fs pulse duration) was used as the excitation and probe light source for Z-scan measurement and ultrafast pump-probe experiment. The nominal thickness of our perovskite films is $\sim 300 \text{ nm}$ that is much smaller than the Rayleigh length (z_0) of $\sim 2 \text{ mm}$. The Z-scan as well as carrier dynamics measurements were repeatedly measured for several sets of samples synthesized under the same growth conditions. The quality of samples were confirmed by XRD and low-temperature photoluminescence measurements [11].

3. Results and discussion

Figure 1(a) and (b) illustrate the top-view scanning electron micrograph (SEM) images of EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ films. EAPbI_3 film shows elongated granular morphology, whereas $(\text{BA})_2\text{PbI}_4$ shows close-packed uniform surface with a fine texture. The sheet-like morphology in $(\text{BA})_2\text{PbI}_4$ characterizes the growth of two-dimensional layered films. Figure 1(c) shows the X-ray diffraction (XRD) curves of EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ films on quartz substrate. XRD structural analysis revealed that EAPbI_3 crystallizes within the orthorhombic lattice with $a = 8.618(4) \text{ \AA}$, $b = 8.030(7) \text{ \AA}$, and $c = 30.119(5) \text{ \AA}$, similar to the structure reported by Park *et al.* [13]. The

structure of $(\text{BA})_2\text{PbI}_4$ has been refined in orthorhombic space group and exhibits the periodicity $b=27.631(1)$ Å along the b -direction, which is typical for 2D perovskites showing a preferential growth along one direction [2].

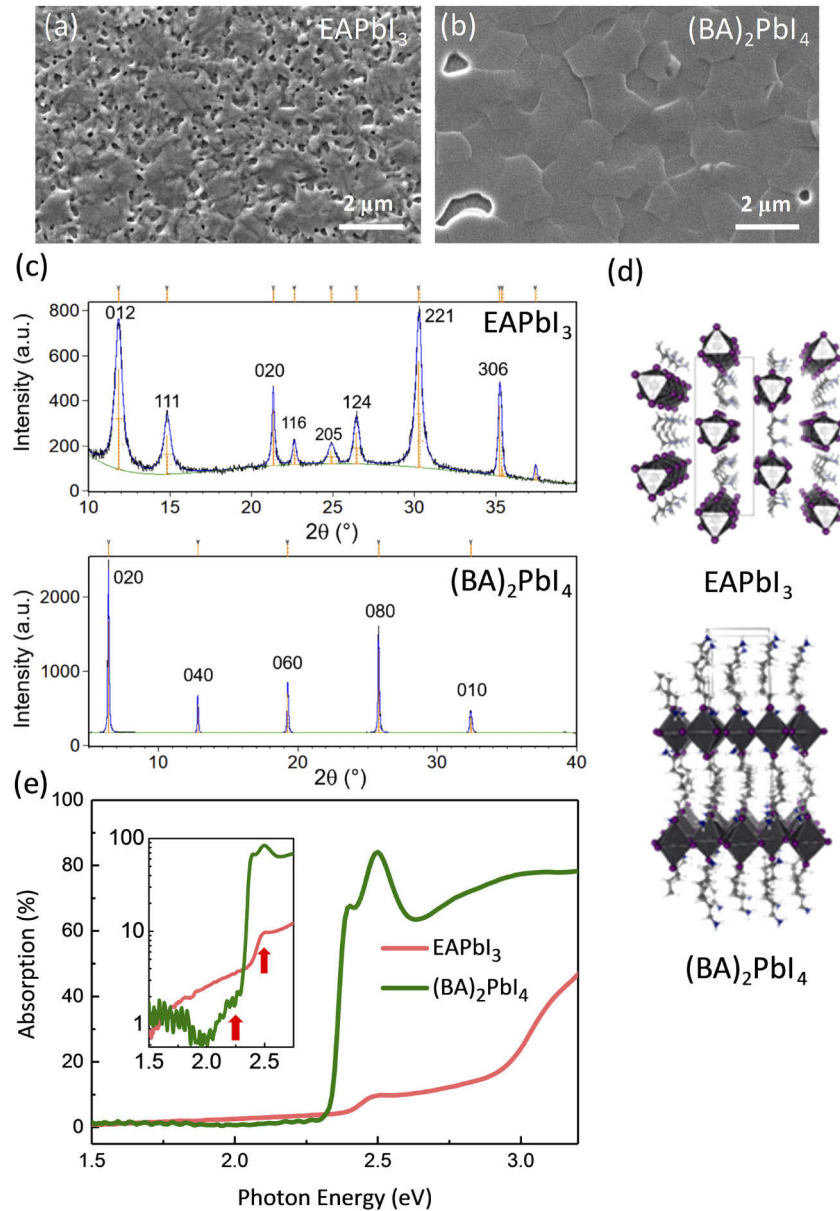


Fig. 1. (a),(b) Top-view SEM images, (c) XRD curves, and (d) Schematic views of crystal structures of the EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ perovskite films. Symbols in (d) represent Pb and its polyhedra in grey, iodide in purple, and nitrogen in blue. (e) Absorption spectra EAPbI_3 and $(\text{BA})_2\text{PbI}_4$. Inset in (e) shows the same absorption spectra in logarithmic scale and red arrows indicate the wavelengths chosen for Z-scan measurement.

Figure 1(d) illustrates the schematics of crystal structures of EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ which depict 1D and 2D arrangements of inorganic octahedron cages separated by alkyl chains of

different lengths. In EAPbI_3 , inorganic octahedra construct 1D networks via face-sharing connectivity, while in $(\text{BA})_2\text{PbI}_4$, corner-sharing inorganic cages form 2D layered structure. Different dimensionality is likely to lead to different physical properties, which are strongly depending on the nature of the cationic elements. Figure 1(e) shows the optical absorption spectra of EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ measured at room temperature. Their direct bandgap properties are characterized by the clear absorption edges locating near 2.35 eV along with the narrow excitonic absorption peaks, particularly pronounced in $(\text{BA})_2\text{PbI}_4$, reflecting the exciton confinement effect in low-dimensional structures. Meanwhile, as can be seen in the inset of Fig. 1(e), the absorption edge of direct-bandgap semiconductor $(\text{BA})_2\text{PbI}_4$ is very steep, whereas the excitonic absorption in EAPbI_3 is relatively weak and there is a reasonable amount of absorption below the band edge.

In order to investigate the optical nonlinear properties, the Z-scan measurements were carried out at wavelengths 500 and 550 nm (two arrows in the inset of Fig. 1(a)). These excitation wavelengths were chosen to probe the nonlinear properties above and below the absorption edge for both samples. Figure 2 shows the typical OA and CA Z-scan data of $(\text{BA})_2\text{PbI}_4$ excited at 500 and 550 nm. In Fig. 2(a), upon excitation at 500 nm where the one-photon absorption dominates, the saturable absorption (SA) behavior is observed and the maximum transmittance at $z=0$ increases nonlinearly as the excitation power density increases. For the below-bandgap excitation at 550 nm, the Z-scan traces in Fig. 2(b) shift to the reverse-saturable absorption (RSA). CA Z-scan data in Fig. 2(c) and (d) also exhibit a transition from self-focusing to self-defocusing behavior under excitation above and below the exciton resonance. The Z-scan data from the bare quartz substrate (black symbols) in Fig. 2(b) confirms that there is no noticeable contribution from the substrate under the same excitation conditions. (CA Z-scan data of substrate are similar and not shown here.) In Z-scan data, scattered data and systematic asymmetry in baselines is often caused by laser instability and surface imperfection and can be corrected by the low intensity background responses [14,15]. Some features appearing in the wing in Fig. 2(b) are possibly due to higher-order nonlinearity.

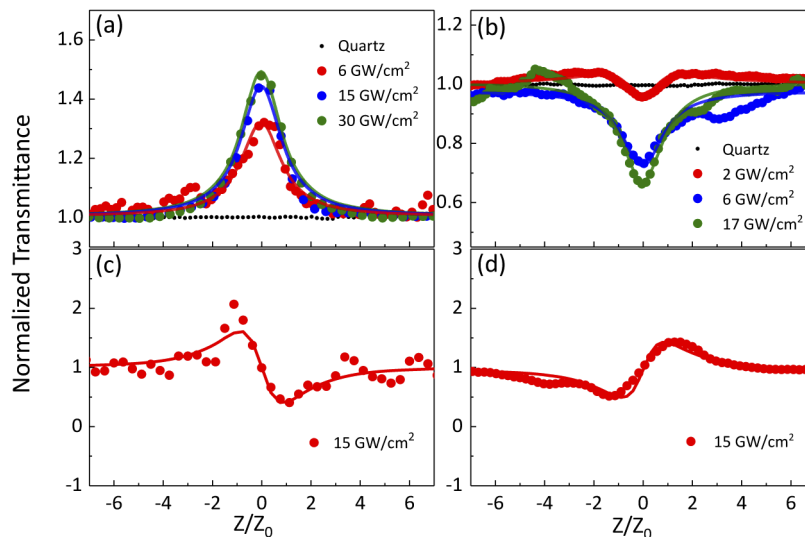


Fig. 2. OA [(a) and (b)] and CA [(c) and (d)] Z-scan traces of $(\text{BA})_2\text{PbI}_4$. (a) and (c) are measured at 500 nm and (b) and (d) are at 550 nm, respectively. Solid curves are the best-fitting results calculated by using formulae in the text.

The transmitted light intensity (I) through the material can be described by [16–18]

$$\frac{dI}{dz} = -[\alpha_0 + \beta(I)I]I, \quad (1)$$

where z is the propagating distance in the sample, α_0 is the linear absorption coefficient, $\beta(I)$ is the intensity-dependent nonlinear absorption coefficient, typically defined as $\beta(I) = \beta_0 / \left(1 + \frac{I}{I_s}\right)$, with I_s the saturable intensity and β_0 the nonlinear absorption coefficient under the low-intensity limit [16]. For saturable absorption, β is a negative value, while for reverse-saturable absorption, such as excited state absorption or two-photon absorption, β is positive. Combining with Gaussian intensity profile of laser beam, one can obtain the expression to fit the z -dependent normalized OA Z-scan data [19],

$$T_{\text{OA}}(z) = 1 - \frac{q_0}{2\sqrt{2}(1+z^2)}, \quad (2)$$

where $q_0 = \beta I_0 L_{\text{eff}}$, L_{eff} is the effective length of the sample calculated by $L_{\text{eff}} = \frac{1-e^{-\alpha_0 L}}{\alpha_0}$ and L is the active length (~ 300 nm) of the sample. In the fitting process, β is a fitting parameter, while α_0 obtained from the optical transmission spectra is fixed to be 3.3×10^3 and $5.7 \times 10^4 \text{ cm}^{-1}$ for EAPbI₃ and (BA)₂PbI₄, respectively. From the best-fits to experimental data (solid curves in Fig. 2(a) and (b)), β at $I = 6 \text{ GW/cm}^2$ are estimated to be -5.3 cm/MW and 4.3 cm/MW for SA and RSA responses, respectively. These values are about two orders of magnitude larger than those of (BA)₂PbI₄ in powder form [7], but are similar to those of another kind of 2D perovskite, phenylethylamine lead iodide ((PEA)₂PbI₄) thin film [8].

The CA (normalized to OA) Z-scan curves in Fig. 2(c) and (d) are fitted by using the relation given as [20,21]

$$T_{\text{CA}}(z) = 1 + \frac{4\Delta\Phi z}{(1+z^2)(9+z^2)}, \quad (3)$$

where $\Delta\Phi = kI_0 L_{\text{eff}} n_2$ is the phase shift, $k = 2\pi/\lambda$ is the wavevector at the pump wavelength λ , and the intensity dependence of refractive index is defined via $n(I) = n_0 + n_2 I$. The estimated value of n_2 at $I \sim 15 \text{ GW/cm}^2$ for (BA)₂PbI₄ films is shifted from -5.2×10^{-11} to $3.5 \times 10^{-11} \text{ cm}^2/\text{W}$ at wavelengths above (500 nm) and below (550 nm) the absorption edge.

Figure 3 depicts the Z-scan data of 1D EAPbI₃ films measured at 500 and 550 nm. Unlike the results of (BA)₂PbI₄, both OA Z-scan curves in Fig. 3(a) and (b) show SA responses without sign-flip of β . The CA Z-scan profiles in Fig. 3(c) and (d) also do not show the transitional behavior, instead, exhibit only self-focusing behavior. Using Eq. (2), β at the excitation wavelength $\lambda_e = 500$ nm is estimated to be -240 cm/MW for $I = 1.5 \text{ GW/cm}^2$, while at 550 nm, it becomes -10 cm/MW . The values of β for EAPbI₃ and (BA)₂PbI₄ are much larger than those of other 2D materials, such as graphene (-0.09 cm/MW) [22] and the saturable intensities are several orders of magnitude larger than that of gallium arsenide ($\sim 79 \text{ GW/cm}^2$) [23].

Besides excitation wavelength, nonlinear optical parameters are functions of the excitation laser intensity and we summarized their relation in Fig. 4(a)–(c). Solid curves in Fig. 4(a) and (b) are obtained from the relation above with fitting parameters listed in Table 1. Fitting parameters of (BA)₂PbI₄ used in Fig. 4(a) are $\beta_0 = -9.6$ and 10.1 cm/MW and $I_s \sim 6.4$ and 4.2 GW/cm^2 for SA and RSA responses, respectively. As is mentioned above, these values are similar to that of 2D (PEA)₂PbI₄ films [8]. It was also reported that (PEA)₂PbI₄ flakes mechanically exfoliated from bulk materials have much higher nonlinear coefficients than polycrystalline thin films [8], indicating that the nonlinear optical parameters of perovskites are strongly influenced by the crystalline quality of samples. Meanwhile, another Z-scan measurement of single-crystalline (BA)₂PbI₄ nanosheets which were also prepared by mechanical exfoliation method shows the transition in sign for both β_0 and n_2 near the plasma frequency (ω_p) and in particular, β becomes significantly large ($< -250 \text{ cm/MW}$) for low intensity excitation [9].

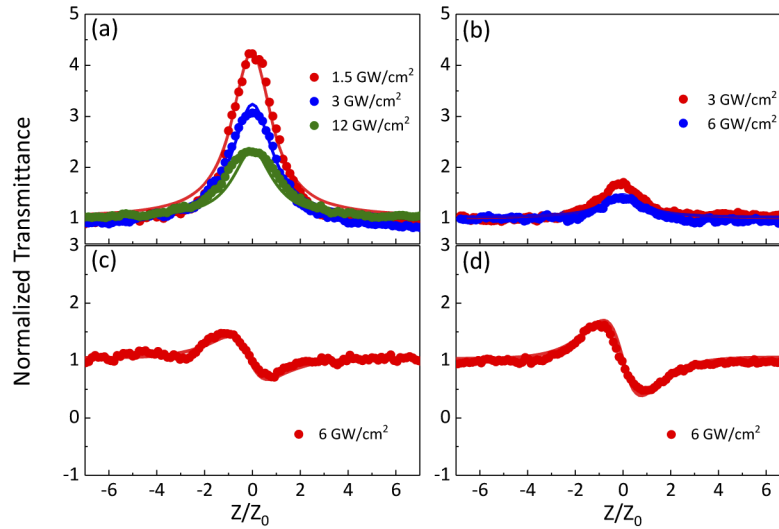


Fig. 3. OA [(a) and (b)] and CA [(c) and (d)] Z-scan traces of EAPbI₃. (a) and (c) are measured at 500 nm and (b) and (d) are at 550 nm, respectively. Solid curves are the best-fitting results calculated by using formulae in the text.

Table 1. Nonlinear optical parameters used in the text

Material	Pump Wavelength (nm)	Nonlinear absorption	β_0 (β'_0) (cm/MW)	I_s ($I_{s,\beta'}$) (GW/cm ²)	n_2 (cm ² /W)
(BA) ₂ PbI ₄	500	SA	-9.6 ± 0.7	6.4 ± 0.8	-5.2×10^{-11}
	550	RSA	10.1 ± 1.4	4.2 ± 0.7	7.1×10^{-11}
EAPbI ₃	500	SA	-310 ± 70 (-216)	1.5 ± 0.4 (0.65)	-3.2×10^{-10}
	550	SA	-18.5 ± 3.5	6.8 ± 1.0	-2.3×10^{-10}

Interestingly, from the curve fitting in Fig. 4(b), β_0 of EAPbI₃ excited at 500 nm is estimated to be as large as -310 cm/MW with much smaller saturation intensity of 1.5 GW/cm². It is noteworthy that this large β_0 is obtained from polycrystalline EAPbI₃ films fabricated by spin-coating method. The nonlinear absorption coefficient significantly decreases as the excitation light intensity increases above the saturable intensity. We also notice that the solid curve in Fig. 4(b) obtained by applying the simple saturable absorption model cannot properly fit the sharp increase (negative value) of β at low intensity. Similarly drastic increase of β at low intensity and the disagreement with the saturable absorption model were previously observed for single crystalline (BA)₂PbI₄ and (PEA)₂PbI₄ [8,9], implying that it is requisite to employ a higher-order nonlinear relation to describe the intensity dependence of nonlinear absorption in high quality low-dimensional perovskites. A plausible fitting to experimental results (dashed line) could be obtained by employing an extended SA model with the additional relation of $\beta'_0 / \left(1 + \frac{I^2}{I_{s,\beta'}^2}\right)$, which has been used to describe the homogeneously broadened system [8,16]. However, it is still an empirical postulation and detailed explanation needs further experimental and theoretical investigation.

A large enhancement of nonlinear absorption in low-dimensional materials is well accepted to be attributed to the resonant enhancement of locally confined excitons [9,16,24]. Excitons in (BA)₂PbI₄ films are tightly localized within 2D layered structures and this strong quantum confinement of excitons leads to a large exciton binding energy (>600 meV) and enables intense

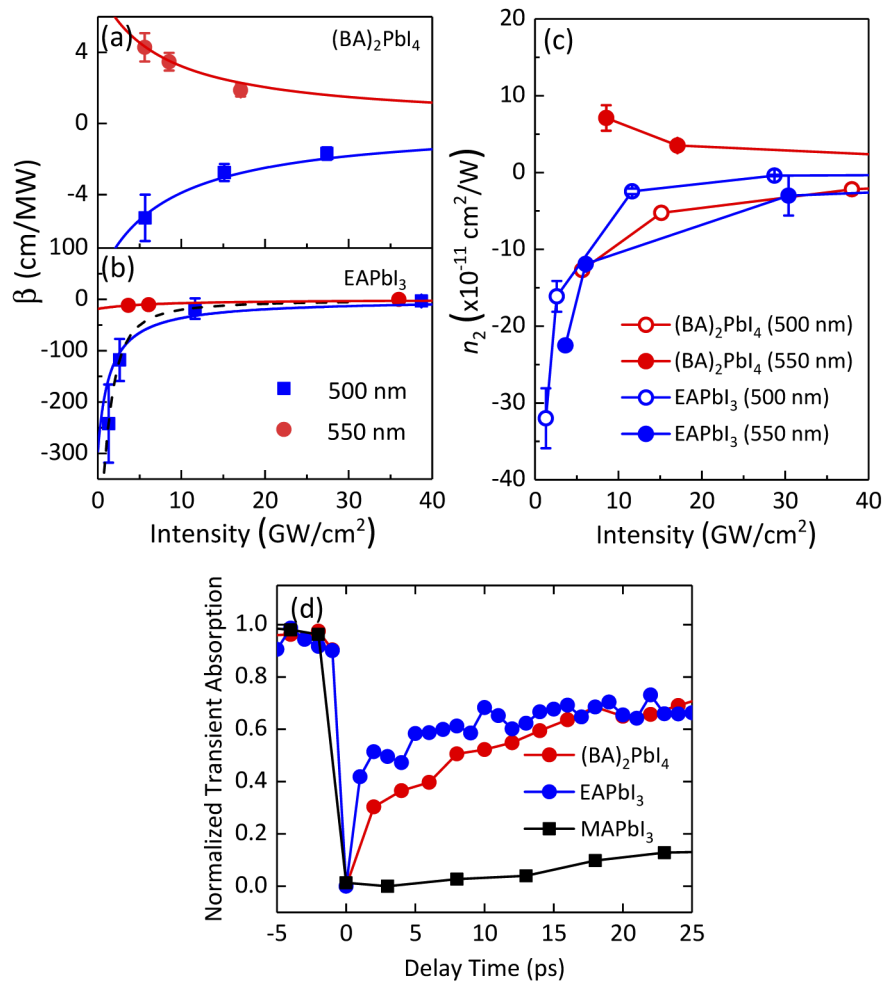


Fig. 4. Excitation light intensity dependence of nonlinear optical coefficients. (a) and (b) are β for (BA)₂PbI₄ and EAPbI₃ perovskites, respectively, and (c) is n_2 for both samples. (d) Normalized transient absorption of (BA)₂PbI₄ and EAPbI₃, compared with that of 3D MAPbI₃.

excitonic emission [11]. However, our results show that EAPbI₃ with much smaller exciton binding energy (~33 meV) possesses higher optical nonlinearity than (BA)₂PbI₄, and it is necessary to consider another approach including dielectric properties [25]. As is depicted in Fig. 1(d), the spin-coated EAPbI₃ film forms a one-dimensional chain structure containing face-sharing PbI₆ octahedra. Since these chain structures are surrounded by organic cation barriers, the dielectric contrast between the inorganic and organic elements in 1D EAPbI₃ can be high and may not be strongly influenced by the crystalline quality of films compared to the layered (BA)₂PbI₄ films, for which the exciton confinement is limited to the direction of layer stacking axis. Therefore, combined with the quantum confinement effect, strong dielectric confinement in EAPbI₃ films may lead to higher optical nonlinearity under much lower intensity excitation than in (BA)₂PbI₄ films. Small and still negative value of β for EAPbI₃ excited at 550 nm may be due to the fast saturation of absorption in tail states and may not be directly related with exciton confinement since RSA is owing to either excited state absorption or two-photon absorption. Figure 4(c) shows that the nonlinear refraction effect is also enhanced at low intensity for EAPbI₃.

In order to understand the exciton dynamics in low-dimensional perovskites, the differential absorption spectra of $(\text{BA})_2\text{PbI}_4$ and EAPbI_3 films are measured by using ultrafast pump-probe measurement. Figure 4(d) illustrates the normalized transient absorption (TA) of perovskite films photoexcited at 400 nm and probed at 500 nm. For low-dimensional perovskites, a sharp negative TA signal due to exciton bleaching quickly recovers within a few picoseconds. In particular, the recovery time of EAPbI_3 film is noticeably faster than that of $(\text{BA})_2\text{PbI}_4$ film. In Fig. 4(d), the TA signal of three-dimensional MAPbI_3 is also exhibited and its relaxation time is much longer (>200 ps) than those of $(\text{BA})_2\text{PbI}_4$ and EAPbI_3 films. Long lifetime of exciton is beneficial for MAPbI_3 -based solar cells, but the fast relaxation time is requisite for all-optical switching. Our results open up potential applications for cost-efficient low-dimensional perovskite-based nonlinear optical devices.

4. Conclusion

Through Z-scan measurements and a comprehensive analysis, we have demonstrated that EAPbI_3 and $(\text{BA})_2\text{PbI}_4$ films with one- and two-dimensional crystal structures have high optical nonlinearities in the visible spectral range. In particular, 1D EAPbI_3 has much higher nonlinear optical properties than those of 2D $(\text{BA})_2\text{PbI}_4$ and a low saturable intensity near the bandedge. Strong quantum confinement of electrons and holes in the layered $(\text{BA})_2\text{PbI}_4$ films leads to a large exciton binding energy and enables intense excitonic emission. Meanwhile, for EAPbI_3 , 1D chain-like structures constructed via face-shared PbI_6 octahedra are surrounded by organic cations, resulting in a relatively small exciton binding energy, but a large dielectric contrast between them. The large optical nonlinearity of polycrystalline EAPbI_3 can thus be attributed to the strong dielectric confinement of excitons along with the quantum confinement. Large nonlinear absorption in 1D EAPbI_3 films is less sensitive to the crystalline quality and polycrystalline EAPbI_3 films fabricated by the simple spin-coating method show high optical nonlinearities comparable to their single-crystalline counterparts. Our results provide a valuable information for the nonlinear optical application of low-dimensional perovskites in the field of compact and cost-efficient photonic systems.

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Disclosures

The authors declare no conflicts of interest.

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